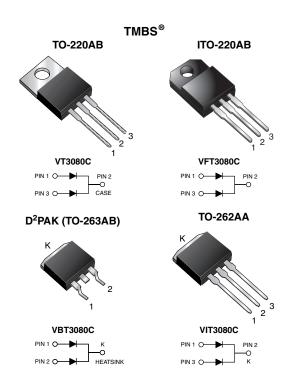
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Vishay General Semiconductor

Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.46 \text{ V}$ at $I_F = 5 \text{ A}$



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V _{RRM}	80 V					
I _{FSM}	150 A					
V _F at I _F = 15 A	0.65 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262A					
Circuit configuration	Common cathode					

FEATURES

Trench MOS Schottky technology



· Low forward voltage drop, low power losses

(e3)

• High efficiency operation

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)

- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D^2PAK (TO-263AB) and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)									
PARAMETER		SYMBOL	VT3080C	VFT3080C	VBT3080C	VIT3080C	UNIT		
Maximum repetitive peak reverse voltage			80						
Mariana and a state of a superior of the state of the sta	per device		30				А		
Maximum average forward rectified current (fig. 1)	per diode	I _{F(AV)}	15						
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			150				Α		
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode			160				mJ		
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode			1.0			Α			
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min			1500			V			
Operating junction and storage temperature range			-55 to +150				°C		



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.52	-	- V		
	I _F = 7.5 A			0.58	=			
	I _F = 15 A			0.75	0.82			
	I _F = 5 A	T _A = 125 °C		0.46	=			
	I _F = 7.5 A			0.52	=			
	I _F = 15 A			0.65	0.70			
Reverse current per diode	V _R = 80 V	$T_A = 25 \degree C$ $T_A = 125 \degree C$	I _R ⁽²⁾	30	700	μA		
	v _R = 60 v			20	35	mA		

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	VT3080C	80C VFT3080C VBT3080C VIT3080C UN				
Typical thermal resistance	per diode	$R_{ heta JC}$	2.5	6.0	2.5	2.5	°C/W	
	per device		2.0	5.0	2.0	2.0		

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	VT3080C-E3/4W	1.89	4W	50/tube	Tube			
ITO-220AB	VFT3080C-E3/4W	1.76	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VBT3080C-E3/4W	1.39	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VBT3080C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VIT3080C-E3/4W	1.46	4W	50/tube	Tube			

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

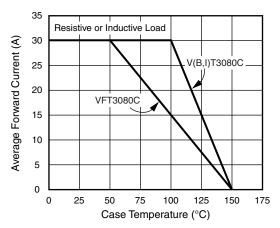


Fig. 1 - Maximum Forward Current Derating Curve

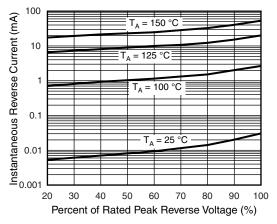


Fig. 4 - Typical Reverse Characteristics Per Diode

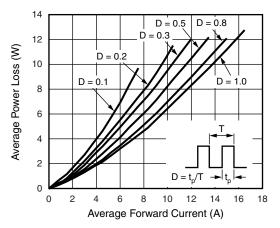


Fig. 2 - Forward Power Loss Characteristics Per Diode

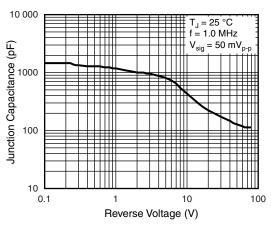


Fig. 5 - Typical Junction Capacitance Per Diode

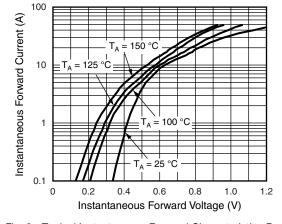


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

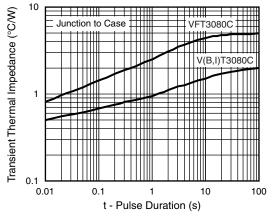
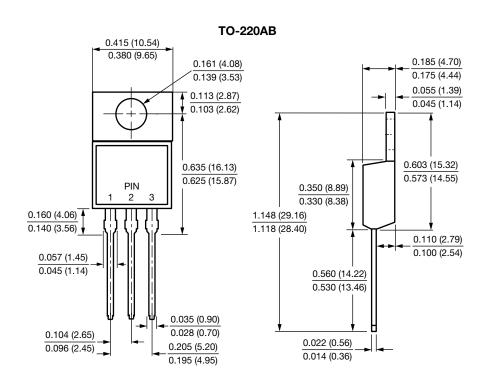


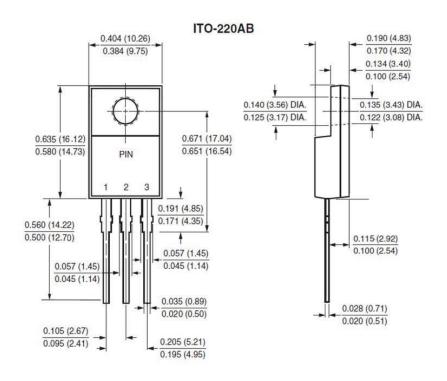
Fig. 6 - Typical Transient Thermal Impedance Per Device

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

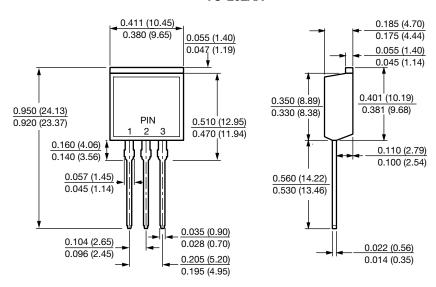




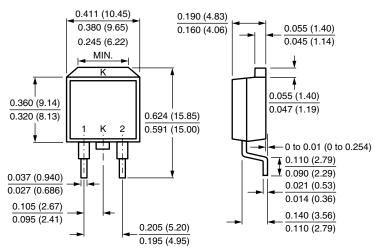
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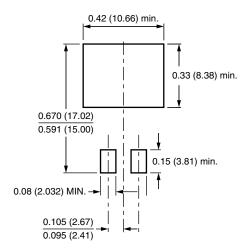
TO-262AA



D²PAK (TO-263AB)



Mounting Pad Layout





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